



Product Datasheet

Longline SSD

Industrial SATA Solid State
Drive 2.5" SATAIII 1.92TB
LNGENTMAX1.92TBSSD



Capacity	Read	Write	Read K IOPS	Write K IOPS	Endurance
1.92TB	550	535	98	85	18.78

Revision History

Revision	Draft Date	History	Author
1.0	2018/12/4	New release	Golden Lee
1.1	2019/4/11	Modify capacity support and power consumption	Golden Lee
1.2	2019/5/10	Update TBW	Golden Lee
1.3	2019/10/4	Update performance / TBW / power consumption	Golden Lee

Product Overview

- **Capacity**
 - 120GB(128GB) up to 1920GB(1.92TB)
- **Form Factor**
 - 2.5" SATA SSD
- **SATA Interface**
 - SATA Revision 3.2
 - SATA 1.5Gbps, 3Gbps, and 6Gbps interface
- **Flash Interface**
 - Flash Type: 3D Bics3 TLC
 - Up to 8pcs of BGA132 flash
- **Performance**
 - Read up to 550 MB/s
 - Write up to 530 MB/s
- **Power Consumption^{Note1}**
 - Idle mode: < 2300 mW
 - Active mode: < 87 mW
- **Reliability**
 - MTBF 1,600,000 hours
 - Uncorrectable Bit Error Rate (UBER)
< 1 sector per 10^{16} bits read

- **Low Power Management**
 - DIPM/HIPM Mode
 - DEVSLP Mode (Optional)
- **Advanced Flash Management**
 - Static and Dynamic Wear Leveling
 - Bad Block Management
 - TRIM
 - SMART
 - Over-Provision
- **Temperature Range**
 - Operation: 0°C ~ 70°C
 - Storage: -40°C ~ 85°C
- **Compliant**
 - RoHS
 - CE & FCC
- **Features Support List:**
 - End to end data path protection
 - Thermal throttling
 - SmartECC™
 - SmartRefresh™
 - Drive log
 - Support of AES/TCG OPAL^{Note2}

Notes:

1. Please see "Power Consumption" for details.
2. Supported by separate firmware version. Further information available upon request.





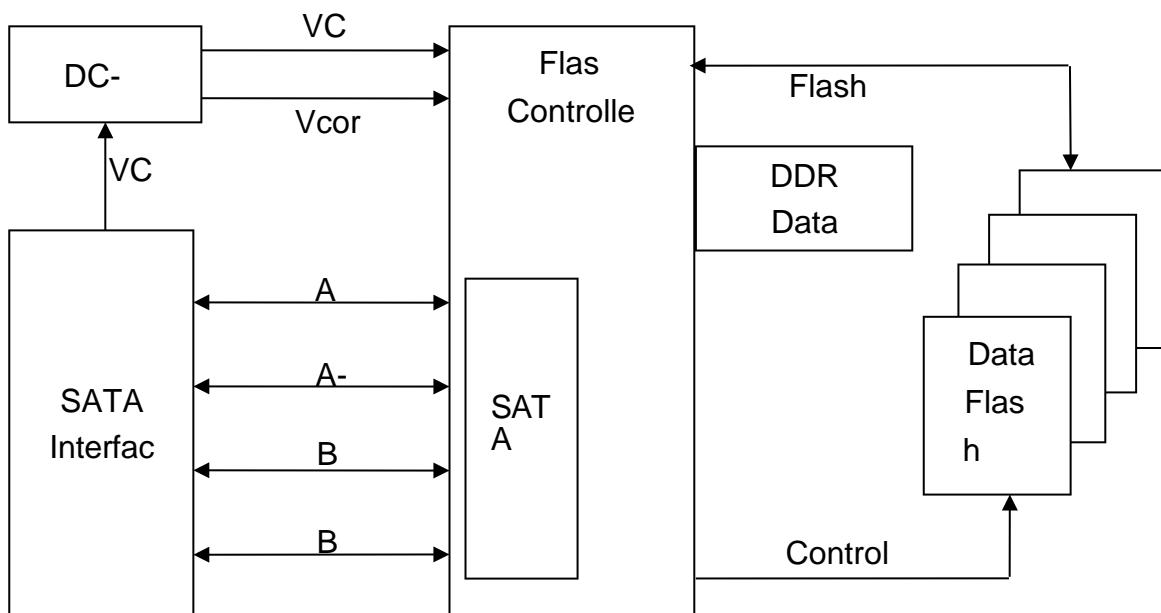
1. INTRODUCTION



1.1. General Description

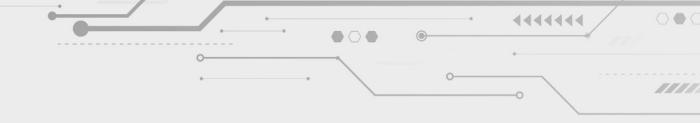
Longline 2.5" SATA SSD delivers all the advantages of flash disk technology with Serial ATA I/II/III interface, including being fully compliant with standard 2.5-inch form factor, providing low power consumption compared to traditional hard drive and hot-swapping when removing/replacing/upgrading flash disks. The device is designed based on the standard 7-pin interface for data segment and 15-pin for power segment, as well as operating at a maximum operating frequency of 400MHz with 25MHz external crystal. Its capacity could provide a wide range up to 1.92TB. Moreover, it can reach up to 550MB/s read as well as 530MB/s write high performance based on Toshiba's 3D TLC NAND flash.

1.2. Block Diagram



2.5" SATA SSD Block Diagram





2. PRODUCT SPECIFICATIONS

- **Capacity**
 - From 120GB(128GB) up to 1920GB(1.92TB)
 - Optional for over-provision
- **Electrical/Physical Interface**
 - SATA Interface
 - ◆ Compliant with SATA Revision 3.2
 - ◆ Compatible with SATA 1.5Gbps, 3Gbps and 6Gbps interface
 - ◆ Support power management
 - ◆ Support expanded register for SATA protocol 48 bits addressing mode
 - ◆ Embedded BIST function for SATA PHY for low cost mass production
- **Supported NAND Flash**
 - Support up to 32 Flash Chip Enables (CE) within single design
 - Support 8pcs BGA132 flash
 - Support OFNI 4.0 & Toggle 2.0 interface
 - Support Toshiba 3D Bics3 TLC
- **ECC Scheme**
 - Applies the LDPC (Low Density Parity Check) of ECC algorithm
- **UART / GPIO function**
- **Support SMART and TRIM commands**

- **Capacity Information**

Capacity	Cylinders	Heads	Sectors	Total Sectors	User Data Size
120GB	16,383	16	63	234,441,648	Depended on file management
128GB	16,383	16	63	250,069,680	
240GB	16,383	16	63	468,862,128	
256GB	16,383	16	63	500,118,192	
480GB	16,383	16	63	937,703,088	
512GB	16,383	16	63	1,000,215,216	
960GB	16,383	16	63	1,875,385,008	
1TB	16,383	16	63	2,000,409,264	
1920GB	16,383	16	63	3,750,748,848	
1.92TB	16,383	16	63	4,000,797,360	



- **Performance**

- **3D Bics3:**

Capacity	Flash Structure	Flash Type	Sequential		Random	
			Read (MB/s)	Write (MB/s)	Read (IOPS)	Write (IOPS)
120GB 128GB	64GB x 2	TSB Bics3, BGA	550	530	86K	90K
240GB 256GB	64GB x 4	TSB Bics3, BGA	550	530	98K	89K
480GB 512GB	64GB x 8	TSB Bics3, BGA	550	530	97K	89K
960GB 1TB	128GB x 8	TSB Bics3, BGA	550	530	98K	89K
1920GB 2TB	256GB x 8	TSB Bics3, BGA	550	530	98K	89K

Notes:

1. The performance was estimated based on Toshiba BiCS3 TLC NAND flash.
2. Performance may differ according to flash configuration and platform.
3. The table above is for reference only. Any criteria for accepting goods shall be discussed based on different flash configuration.
4. Performance is measured with the following conditions
 - (a) CrystalDiskMark 6.0.0, 1GB range, QD32
 - (b) IO Meter, 1GB range, 4K datasize, QD32
5. Drive Writes Per Day (DWPD) is 5

- **TBW (Terabytes Written)**

- **3D Bics3:**

Capacity	Flash Type	TBW
128GB	TSB Bics3	1500
256GB	TSB Bics3	2620
512GB	TSB Bics3	4878
1024GB	TSB Bics3	8925
2048GB	TSB Bics3	18026

Notes:

1. Samples were built using Toshiba BiCS3 TLC NAND flash.
2. The test followed JEDEC219A client endurance workload.
3. TBW may differ according to flash configuration and platform.
4. The endurance of SSD could be estimated based on user behavior, NAND endurance cycles, and write amplification factor. It is not guaranteed by flash vendor.



3. ENVIRONMENTAL SPECIFICATIONS

3.1. Environmental Conditions

3.1.1. Temperature and Humidity

- Temperature:
 - ◆ Storage: -40°C to 85°C
 - ◆ Operational: 0°C to 70°C

■ High Temperature Test Condition

	Temperatur e	Humidit y
Operatio n	70°C	0% RH
Storage	85°C	0% RH

■ Low Temperature Test Condition

	Temperatur e	Humidit y
Operatio n	0°C	0% RH
Storage	-40°C	0% RH

■ High Humidity Test Condition

	Temperatur e	Humidit y
Operation (Standard)	40°C	90% RH
Storage (Standard)	40°C	93% RH

■ Temperature Cycle Test

	Temperatur e
Operatio n	0°C
	70°C ^{Note}
Storage	-40°C
	85°C

Notes:

1. Operation temperature is measured by device temperature sensor. Airflow is suggested and it will allow device to be operated at appropriate temperature for each component during heavy workloads environment.
2. Operation temperature shows in case temperature not ambient temperature.





3.1.2. Shock

■ Shock Specification

	Acceleration Force	Number of Shock
Non-operational	1500G	6 faces of each unit 3 times for each face

3.1.3. Vibration

■ Vibration Specification

	Condition	
	Frequency/Displacement	Frequency/Acceleration
Non-operational	20Hz~80Hz/1.52mm	80Hz~2000Hz/20G

3.1.4. Drop

■ Drop Specification

	Height of Drop	Number of Drop
Non-operational	80cm free fall	6 face of each unit

3.1.5. Bending

■ Bending Specification

	Force	Action
Non-operational	≥ 50N	Hold 1min/5times

3.1.6. Durability

■ Durability Specification

	Condition
Non-operational	1000 mating cycles

3.1.7. Electrostatic Discharge (ESD)

■ Contact ESD Specification

Specification	+/- 4KV
EN 55024, CISPR 24	Device functions are affected, but EUT will be back to its normal or operational state automatically.
EN 61000-4-2 and IEC 61000-4-2	



3.1.8. EMI Compliance

	Specificati
FCC:	CISPR2
2 CE:	EN5502
2	

3.2. MTBF

MTBF, Mean Time Between Failures, is a measure of reliability of a device. Its value represents the average time between a repair and the next failure. The unit of MTBF is in hours. The higher the MTBF value, the higher the reliability of the device.

Our MTBF result is based on simulation software (Brand/Model). Please note that a lower MTBF should be expected for higher capacity drives, and we apply the lowest MTBF for all capacities.

3.3. Certification

- RoHS
- CE / FCC

3.4. Compliance

- SATA III (SATA Rev. 3.2)
- Up to ATA/ATAPI-8 (Including S.M.A.R.T)





4. ELECTRICAL SPECIFICATIONS

4.1. Supply Voltage

Parameter	Rating
Operating Voltage	5V ± 5%
Rise Time (Max/Min)	100ms / 0.1ms
Fall Time (Max/Min)	5s / 1ms
Min. off Time	1s

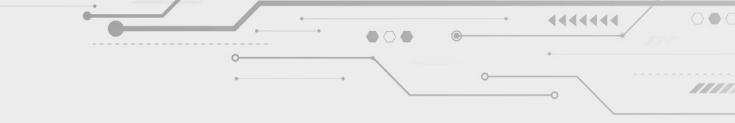
4.2. Power Consumption

■ 3D Bics3

Capacity	Flash Structure	Flash Type	CE#	Read	Write	Partial	Standby	Idle
120GB 128GB	64GB x 2	TSB Bics3, BGA	4	1,300	1,100	20	14	87
240GB 256GB	64GB x 4	TSB Bics3, BGA	8	2,100	1,800	21	17	66
480GB 512GB	64GB x 8	TSB Bics3, BGA	16	2,100	1,800	21	17	66
960GB 1TB	128GB x 8	TSB Bics3, BGA	32	2,200	1,800	19	14	64
1920GB	256GB x 8	TSB Bics3, BGA	32	2,300	2,000	36	32	Unit: mW

Notes:

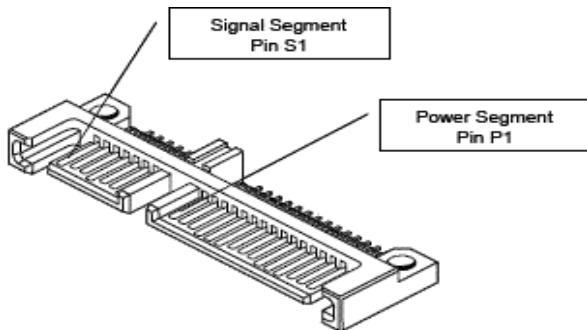
1. Based on SCFM1xxx-series under ambient temperature.
2. The measured power voltage is 5V.
3. Use CrystalDiskMark 6.0.0 with the setting of 1000MB. Sequentially read and write the disk for 5 times, and measure power consumption during sequential Read [1/5]~[5/5] or sequential Write [1/5]~[5/5]
4. Power Consumption may differ according to flash configuration and platform.



5. INTERFACE



5.1. Pin Assignment and Descriptions



- Signal Segment Pin Assignment and Description

Pin Number	Function
S1	GND
S2	A+ (Differential Signal Pair A)
S3	A- (Differential Signal Pair A)
S4	GND
S5	B- (Differential Signal Pair B)
S6	B+ (Differential Signal Pair B)
S7	GND

- Power Segment Pin Assignment and Description

Pin Number	Function
P1	Not Used (3.3V)
P2	Not Used (3.3V)
P3	DEVSLP
P4	GND
P5	GND
P6	GND
P7	5V pre-charge
P8	5V
P9	5V
P10	GND
P11	Reserved (DAS)
P12	GND
P13	Not Used (12V pre-charge)
P14	Not Used (12V)
P15	Not Used (12V)





6. SUPPORTED COMMANDS



6.1. ATA Command List

Op Code	Suppor t	Description	Op Code	Suppor t	Description
00h	Y	NOP	B6h	12h	- NV Cache: QUERY NV CACHE PINNED SET DMA EXT
03h	-	CFA REQUEST EXTENDED ERROR	B6h	13h	- NV Cache: QUERY NV CACHE MISSES DMA EXT
06h	Y	DATA SET MANAGEMENT	B6h	14h	- NV Cache: FLUSH NV CACHE
08h	-	DEVICE RESET	C4h	Y	READ MULTIPLE
0Bh	-	REQUEST SENSE DATA EXT	C5h	Y	WRITE MULTIPLE
10h	Y	RECALIBRATE	C6h	Y	SET MULTIPLE MODE
11h-1Fh	-	RECALIBRATE	C7h	-	READ DMA QUEUED
20h	Y	READ SECTOR(S)	C8h	Y	READ DMA
21h	Y	READ SECTOR(S) WITHOUT RETRY	C9h	Y	READ DMA WITHOUT RETRY
22h	-	READ LONG	CAh	Y	WRITE DMA
23h	-	READ LONG WITHOUT RETRY	CBh	Y	WRITE DMA WITHOUT RETRY
24h	Y	READ SECTOR(S) EXT	CCh	-	WRITE DMA QUEUED
25h	Y	READ DMA EXT	CDh	-	CFA WRITE MULTIPLE WITHOUT ERASE
26h	-	READ DMA QUEUED EXT	CEh	Y	WRITE MULTIPLE FUA EXT
27h	Y	READ NATIVE MAX ADDRESS EXT	D1h	-	CHECK MEDIA CARD TYPE
29h	Y	READ MULTIPLE EXT	DAh	-	GET MEDIA STATUS
2Ah	-	READ STREAM DMA EXT	DEh	-	MEDIA LOCK
2Bh	-	READ STREAM EXT	DFh	-	MEDIA UNLOCK
2Fh	Y	READ LOG EXT	E0h	Y	STANDBY IMMEDIATE
30h	Y	WRITE SECTOR(S)	E1h	Y	IDLE IMMEDIATE
31h	Y	WRITE SECTOR(S) WITHOUT RETRY	E2h	Y	STANDBY
32h	-	WRITE LONG	E3h	Y	IDLE
33h	-	WRITE LONG WITHOUT RETRY	E4h	Y	READ BUFFER
34h	Y	WRITE SECTOR(S) EXT	E5h	Y	CHECK POWER MODE
35h	Y	WRITE DMA EXT	E6h	Y	SLEEP



36h	-	WRITE DMA QUEUED EXT	E7h	Y	FLUSH CACHE
37h	Y	SET MAX ADDRESS EXT	E8h	Y	WRITE BUFFER

Op Code	Suppor t	Description	Op Code	Suppor t	Description
38h	-	CFA WRITE SECTORS WITHOUT ERASE	E9h	Y	READ BUFFER DMA
39h	Y	WRITE MULTIPLE EXT	EA h	Y	FLUSH CACHE EXT
3Ah	-	WRITE STREAM DMA EXT	EB h	Y	WRITE BUFFER DMA
3Bh	-	WRITE STREAM EXT	EC h	Y	IDENTIFY DEVICE
3Ch	-	WRITE VERIFY	ED h	-	MEDIA EJECT
3Dh	Y	WRITE DMA FUA EXT	EE h	-	IDENTIFY DEVICE DMA
3Eh	-	WRITE DMA QUEUED FUA EXT	EF h	01h	SET FEATURES: Enable 8-bit PIO transfer mode (CFA feature set only)
3Fh	Y	WRITE LOG EXT	EF h	02h	SET FEATURES: Enable write cache
40h	Y	READ VERIFY SECTOR(S)	EF h	03h	SET FEATURES: Set transfer mode based on value in Count field
41h	Y	READ VERIFY SECTOR(S) WITHOUT RETRY	EF h	05h	SET FEATURES: Enable advanced power management
42h	Y	READ VERIFY SECTOR(S) EXT	EF h	06h	SET FEATURES: Enable Power-Up In Standby feature set
44h	-	Reserved	EF h	07h	SET FEATURES: Power-Up In Standby feature set device spin-up
45h	O	WRITE UNCORRECTABLE EXT	EF h	0Ah	SET FEATURES: Enable CFA power mode 1
47h	Y	READ LOG DMA EXT	EF h	0Bh	SET FEATURES: Enable Write-Read-Verify feature set
50h	-	FORMAT TRACK	EF h	10h 01h	SET FEATURES: Enable use of Serial ATA feature
51h	-	CONFIGURE STREAM	EF h	10h 02h	SET FEATURES: Enable DMA Setup FIS Auto-Activate optimization

57h	Y	WRITE LOG DMA EXT	EF h	10h	03h	Y	SET FEATURES: Enable Device-initiated interface power state (DIPM) transitions
60h	Y	READ FPDMA QUEUED	EF h	10h	04h	-	SET FEATURES: Enable use of Serial ATA feature
61h	Y	WRITE FPDMA QUEUED	EF h	10h	05h	-	SET FEATURES: Enable use of Serial ATA feature
70h	Y	SEEK	EF h	10h	06h	O	SET FEATURES: Enable Software Settings Preservation (SSP)

Op Code	Suppor t	Description	Op Code	Suppor t	Description
71-76h	-	SEEK	EF h	10h	07h
77h	Y	SET DATE AND TIME EXT	EF h	10h	09h
78h	Y	ACCESSIBLE MAX ADDRESS CONFIGURATION	EF h	42h	-
79-7Fh	-	SEEK	EF h	43h	-
87h	-	CFA TRANSLATE SECTOR	EF h	44h	-
90h	Y	EXECUTE DEVICE DIAGNOSTIC	EF h	55h	Y
91h	Y	INITIALIZE DEVICE PARAMETERS	EF h	5Dh	-
92h	Y	DOWNLOAD MICROCODE	EF h	5Eh	-
93h	Y	DOWNLOAD MICROCODE DMA	EF h	5Fh	-
94h	-	STANDBY IMMEDIATE	EF h	66h	Y
95h	-	IDLE IMMEDIATE	EF h	81h	-
96h	-	STANDBY	EF h	82h	Y

97h	-	IDLE	EF h	85h		Y	SET FEATURES: Disable advanced power management
98h	-	CHECK POWER MODE	EF h	86h		-	SET FEATURES: Disable Power-Up In Standby feature set
99h	-	SLEEP	EF h	8Ah		-	SET FEATURES: Disable CFA power mode
A0h	-	PACKET	EF h	8Bh		-	SET FEATURES: Disable Write-Read-Verify feature set
A1h	-	IDENTIFY PACKET DEVICE	EF h	90h	01h	-	SET FEATURES: Disable use of Serial ATA feature
A2h	-	SERVICE	EF h	90h	02h	Y	SET FEATURES: Disable DMA Setup FIS Auto-Activate optimization

Op Code		Suppor t	Description	Op Code			Suppor t	Description
B0h	D0h	Y	SMART: READ DATA	EFh	90h	03h	Y	SET FEATURES: Disable Device-initiated interface power state (DIPM) transitions
B0h	D1h	Y	SMART: READ ATTRIBUTE THRESHOLDS	EF h	90h	04h	-	SET FEATURES: Disable use of Serial ATA feature
B0h	D2h	Y	SMART: ENABLE/DISABLE AUTOSAVE	EF h	90h	05h	-	SET FEATURES: Disable use of Serial ATA feature
B0h	D3h	Y	SMART: SAVE ATTRIBUTE VALUES	EF h	90h	06h	Y	SET FEATURES: Disable Software Settings Preservation (SSP)
B0h	D4h	Y	SMART: EXECUTE OFF-LINE IMMEDIATE	EF h	90h	07h	Y	SET FEATURES: Disable Device Automatic Partial to Slumber transitions
B0h	D5h	Y	SMART: READ LOG	EF h	90h	09h	O	SET FEATURES: Disable Device Sleep
B0h	D6h	Y	SMART: WRITE LOG	EF h	AAh		Y	SET FEATURES: Enable read look-ahead feature
B0h	D8h	Y	SMART: ENABLE OPERATIONS	EF h	BBh		-	SET FEATURES: Default ECC byte
B0h	D9h	Y	SMART: DISABLE OPERATIONS	EF h	C2h		-	SET FEATURES: Disable Automatic Acoustic Management feature set
B0h	DAh	Y	SMART: RETURN STATUS	EF h	C3h		-	SET FEATURES: Enable/Disable the Sense Data Reporting feature set

B0h	DBh	Y	SMART: ENABLE/DISABLE AUTOMATIC OFF-LINE	EFh	CCh	Y	SET FEATURES: Enable reverting to power-on defaults
B0h	E0h	-	SMART: Vendor specific	EFh	DDh	-	SET FEATURES: Disable release interrupt
B1h	C0h	Y	DEVICE CONFIGURATION: RESTORE	EFh	DEh	-	SET FEATURES: Disable SERVICE interrupt
B1h	C1h	Y	DEVICE CONFIGURATION: FREEZE LOCK	EFh	DFh	-	SET FEATURES: Disable NDRQ Feature
B1h	C2h	Y	DEVICE CONFIGURATION: IDENTIFY	F1h		Y	SECURITY SET PASSWORD
B1h	C3h	Y	DEVICE CONFIGURATION: SET	F2h		Y	SECURITY UNLOCK
B1h	C4h	Y	DEVICE CONFIGURATION: IDENTIFY DMA	F3h		Y	SECURITY ERASE PREPARE
B1h	C5h	Y	DEVICE CONFIGURATION: SET DMA	F4h		Y	SECURITY ERASE UNIT

Op Code	Suppor t	Description	Op Code	Suppor t	Description
B4h 0000h	O	SANITIZE DEVICE: SANITIZE STATUS EXT	F5h	Y	SECURITY FREEZE LOCK
B4h 0011h	O	SANITIZE DEVICE: CRYPTO SCRAMBLE EXT	F6h	Y	SECURITY DISABLE PASSWORD
B4h 0012h	O	SANITIZE DEVICE: BLOCK ERASE EXT	F8h	Y	READ NATIVE MAX ADDRESS
B4h 0014h	O	SANITIZE DEVICE: OVERWRITE EXT	F9h 00h	Y	SET MAX: SET MAX ADDRESS
B4h 0020h	O	SANITIZE DEVICE: SANITIZE FREEZE LOCK EXT	F9h 01h	Y	SET MAX: SET MAX PASSWORD
B4h 0040h	O	SANITIZE DEVICE: SANITIZE ANTIFREEZE LOCK EXT	F9h 02h	Y	SET MAX: SET MAX LOCK
B6h 00h	-	NV Cache: SET NV CACHE POWER MODE EXT	F9h 03h	Y	SET MAX: SET MAX UNLOCK
B6h 01h	-	NV Cache: RETURN FROM NV CACHE POWER MODE EXT	F9h 04h	Y	SET MAX: SET MAX FREEZE LOCK
B6h 10h	-	NV Cache: ADD LBA(S) TO NV CACHE PINNED SET DMA	F9h 05h	Y	SET MAX: SET MAX SET PASSWORD DMA



			EXT				
B6h	11h	-	NV Cache: REMOVE LBA(S) FROM NV CACHE PINNED SET DMA EXT	F9h	06h	Y	SET MAX: SET MAX UNLOCK DMA

Notes:

"Y" means "Support".

"O" means "Option, default not support". "-" means "Not support".

6.2. Identify Device Data

The following table details the sector data returned by the IDENTIFY DEVICE command of ATA8-ACS4 SPEC.

Word	F: Fixed V: Variable X: retired/obsolet e /reserved	Default Value	Description
0	F	0040h	General configuration bit-significant information
1	X	*1	Obsolete – Number of logical cylinders
2	F	C837h	Specific configuration
3	X	0010h	Obsolete – Number of logical heads (16)
4-5	X	00000000h	Retired
6	X	003Fh	Obsolete – Number of logical sectors per logical track (63)
7-8	X	00000000h	Reserved for assignment by the Compact Flash Association
9	X	0000h	Retired
10-19	V	Varies	Serial number (20 ASCII characters)
20-21	X	0000h	Retired
22	X	0000h	Obsolete
23-26	V	Varies	Firmware revision (8 ASCII characters)
27-46	V	Varies	Model number (xxxxxxxx)
47	F	8010h	7:0- Maximum number of sectors transferred per interrupt on MULTIPLE commands
48	F	4000h	Reserved
49	F	2F00h	Capabilities
50	F	4000h	Capabilities
51-52	X	00000000h	Obsolete
53	F	0007h	Words 88 and 70:64 valid
54	X	*1	Obsolete – Number of logical cylinders
55	X	0010h	Obsolete – Number of logical heads (16)
56	X	003Fh	Obsolete – Number of logical sectors per track (63)
57-58	X	*2	Obsolete – Current capacity in sectors
59	F	0110h	Number of sectors transferred per interrupt on MULTIPLE commands
60-61	V	*3	Maximum number of sector (28bit LBA mode)
62	X	0000h	Obsolete

63	F	0407h	Multi-word DMA modes supported/selected
Word	F: Fixed V: Variable	Default Value	Description
	X: retired/obsolete /reserved		
64	F	0003h	PIO modes supported
65	F	0078h	Minimum Multiword DMA transfer cycle time per word
66	F	0078h	Manufacturer's recommended Multiword DMA transfer cycle time
67	F	0078h	Minimum PIO transfer cycle time without flow control
68	F	0078h	Minimum PIO transfer cycle time with IORDY flow control
69	F	1F00h	Additional Supported
70	X	0000h	Reserved
71-74	X	000000000000 0000h	Reserved for the IDENTIFY PACKET DEVICE command
75	F	001Fh	Queue depth
76	F	850Eh	Serial SATA capabilities
77	F	0006h	Supported Serial ATA Phy speed
78	F	004Ch	Serial ATA features supported
79	F	0040H	Serial ATA features enabled
80	F	0FF8h	Major Version Number
81	F	0000h	Minor Version Number
82	F	746Bh	Command set supported
83	F	7D01h	Command set supported
84	F	4163h	Command set/feature supported extension
85	F	7469h	Command set/feature supported or enabled
86	F	BC01h	Command set/feature supported or enabled
87	F	4163h	Command set/feature supported or enabled
88	F	007Fh	Ultra DMA Modes
89	F	000Ah	Time required for Normal Erase mode SECURITY ERASE UNIT command
90	F	001Eh	Time required for an Enhanced Erase mode SECURITY ERASE UNIT command
91	F	0000h	Current advanced power management value
92	F	FFF Eh	Master Password Revision Code



93	F	0000h	Hardware reset result. The contents of the bits (12:0) of this word can be changed only during the execution of hardware reset.
Word	F: Fixed V: Variable X:	Default Value	Description
	retired/obsolete /reserved		
94	X	0000h	Vendor's recommended and actual acoustic management value
95	F	0000h	Stream Minimum Request Size
96	F	0000h	Streaming Transfer Time – DMA
97	F	0000h	Streaming Access Latency – DMA and PIO
98-99	F	0000h	Streaming Performance Granularity
100-103	V	*4	Maximum user LBA for 48 bit Address feature set
104	F	0000h	Streaming Transfer Time – PIO
105	F	0008h	Maximum number of 512-byte blocks per DATA SET MANAGEMENT command
106	F	4000h	Physical sector size/Logical sector size
107	F	0000h	Inter-seek delay for ISO-7779 acoustic testing in microseconds
108-111	F	Varies	Reserved
112-115	X	0000000000000000 0000h	Reserved
116	X	0000h	Reserved
117-118	F	00000000h	Words per logical Sector
119	F	401Ch	Supported settings
120	F	401Ch	Command set/Feature Enabled/Supported
121-126	X	0h	Reserved
127	X	0h	Obsolete
128	F	0021h	Security status
129-159	V	Varies	Vendor specific
160	X	0h	Compact Flash Association (CFA) power mode 1
161-167	X	0h	Reserved for assignment by the CFA
168	V	Varies	Device Nominal Form Factor



169	F	0001h	DATA SET MANAGEMENT command is supported
170-173	F	0h	Additional Product Identifier
174-175	X	0h	Reserve
176-205	F	0h	Current media serial number
206	F	0039h	SCT Command Transport(
Word	F: Fixed V: Variable X: retired/obsolete /reserved	Default Value	Description
207-208	X	0h	Reserved
209	F	4000h	Alignment of logical blocks within a physical block
210-211	F	0000h	Write-Read-Verify Sector Count Mode 3 (not support)
212-213	F	0000h	Write-Read-Verify Sector Count Mode 2 (not support)
214-216	X	0000h	NV Cache relate (not support)
217	F	0001h	Non-rotating media device
218	X	0h	Reserved
219	X	0h	NV Cache relate (not support)
220	V	0h	Write read verify feature set current mode
221	X	0h	Reserved
222	F	10FFh	Transport major version number
223	F	0h	Transport minor version number
224-229	X	0h	reserved
230-233	F	0h	Extend number of user addressable sectors
234	F	0001h	Minimum number of 512-byte data blocks per DOWNLOAD MICROCODE command for mode 03h
235	F	FFF Eh	Maximum number of 512-byte data blocks per DOWNLOAD MICROCODE command for mode 03h
236-242	X	0h	Reserved
243	X	0000h	Reserved
244-254	X	0h	Reserved
255	F	XXA5h XX is variable	Integrity word (Checksum and Signature)





■ List of Device Identification for Each Capacity

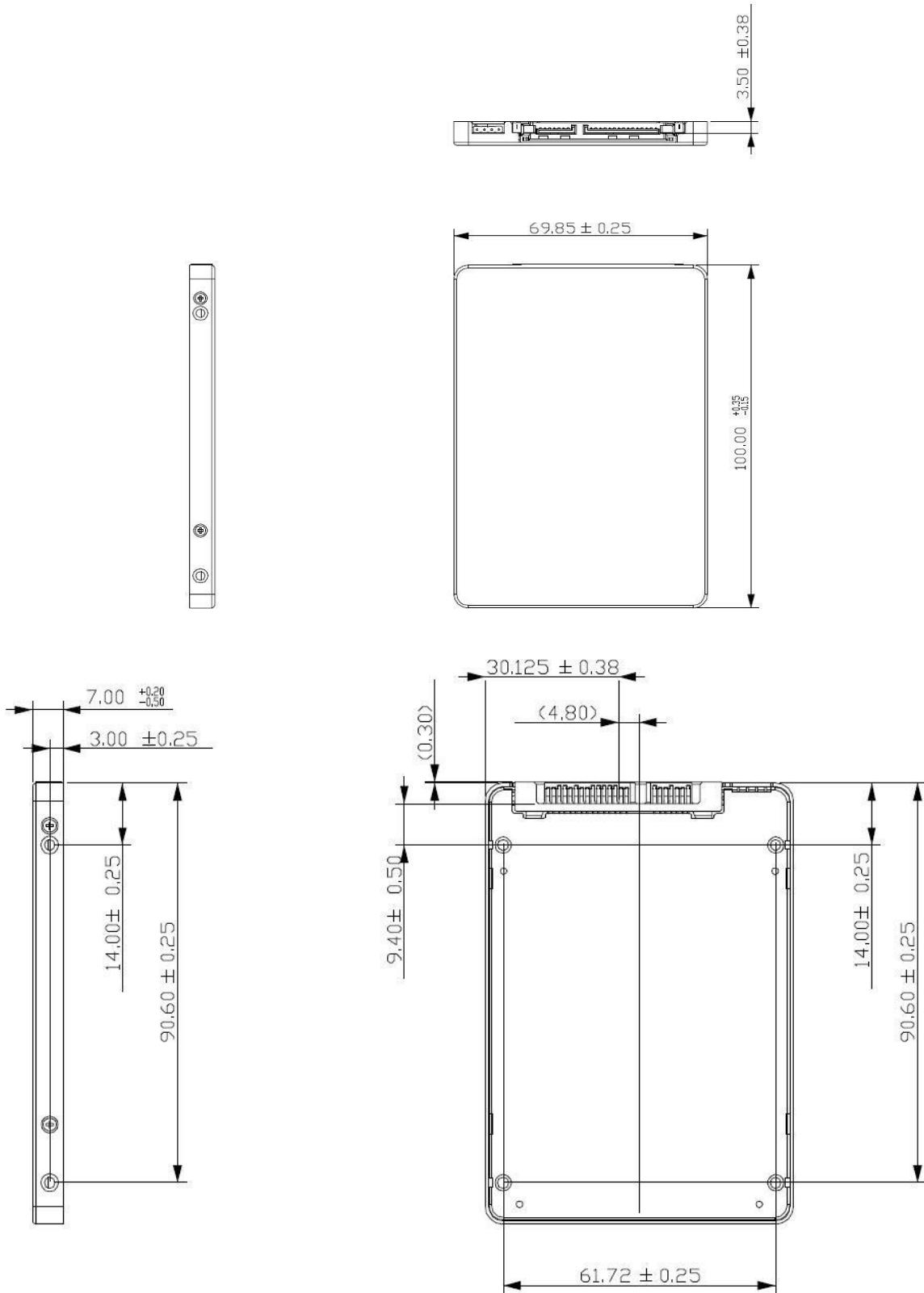
Capacity (GB)	*1 (Word 1/Word 54)	*2 (Word 57– 58)	*3 (Word 60– 61)	*4 (Word 100– 103)
120	3FFFh	FBFC10h	DF94BB0h	DF94BB0h
128	3FFFh	FBFC10h	EE7C2B0h	EE7C2B0h
240	3FFFh	FBFC10h	0FFFFFFFh	1BF244B0h
256	3FFFh	FBFC10h	0FFFFFFFh	1DCF32B0h
480	3FFFh	FBFC10h	0FFFFFFFh	37E436B0
512	3FFFh	FBFC10h	0FFFFFFFh	3B9E12B0h
960	3FFFh	FBFC10h	0FFFFFFFh	6FC81AB0h
1024	3FFFh	FBFC10h	0FFFFFFFh	773BD2B0h
1920	3FFFh	FBFC10h	0FFFFFFFh	DF8FE2B0h
2048	3FFFh	FBFC10h	0FFFFFFFh	EE7752B0h



7. PHYSICAL DIMENSION



Dimension: 100mm(L) x 69.85mm(W) x 7.00mm(H)





8. TERMINOLOGY



The following table is to list out the acronyms that have been applied throughout the document.

Term	Definitions
ATTO	Commercial performance benchmark application
DDR	Double data rate (SDRAM)
DIPM	Device initiated power management
HIPM	Host initiated power management
LBA	Logical block addressing
MB	Mega-byte
MTBF	Mean time between failures
NCQ	Native command queue
SATA	Serial advanced technology attachment
S.M.A.R.T.	Self-monitoring, analysis and reporting technology
SSD	Solid state disk

